NPN Epitaxial Planar Silicon Transistor



2SC4855

# Low-Voltage, Low-Current& **High-Frequency Amplifier Applications**

### **Features**

· Low-voltage, low-current operation : f<sub>T</sub>=5GHz typ.  $(V_{CE}=1V, I_{C}=1mA) : |S21e|^2=7.5dB \text{ typ}$ 

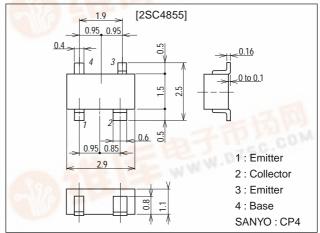
(f=1GHz).

: NF=2.6dB typ (f=1GHz).

## **Package Dimensions**

unit:mm

2110A



WWW.DZ

# **Specifications**

### Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit	
Collector-to-Base Voltage	V <sub>СВО</sub>		12	V	
Collector-to-Emitter Voltage	VCEO		6	V	
Emitter-to-Base Voltage	V <sub>EBO</sub>	pail.	1.5	V	
Collector Current	IC		15	mA	
Collector Dissipation	PC	and the state of the last	80	mW	
Junction Temperature	Tj	A THE THE W	150	°C	
Storage Temperature	Tstg	180	-55 to +150	°C	

#### Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions		Ratings		
	Symbol	Conditions		typ	max	Unit
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =5V, I <sub>E</sub> =0			1.0	μA
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =1V, I <sub>C</sub> =0			10	μA
DC Current Gain	h <sub>FE</sub>	V <sub>CE</sub> =1V, I <sub>C</sub> =1mA	60	*	270*	
Gain-Bandwidth Product	fT	V <sub>CE</sub> =1V, I <sub>C</sub> =1mA		5		GHz
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =1V, f=1MHz		0.6	1.0	pF

\*: The 2SC4855 is classified by 1mA hFE as follows:

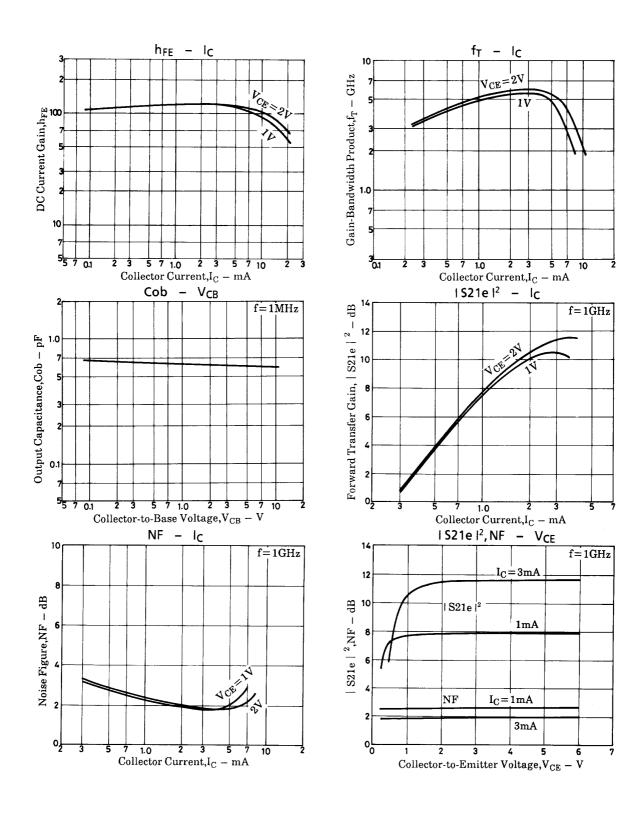
3 120 90 4 180 135

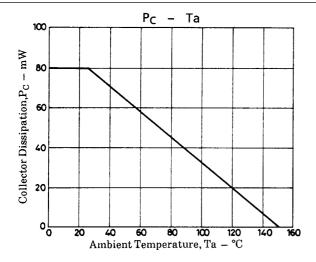
Marking: CN h<sub>FE</sub> rank: 3, 4, 5

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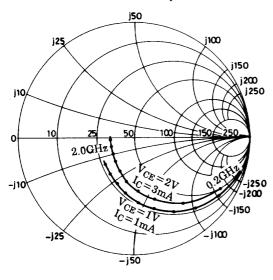
Parameter	Symbol	Conditions		Ratings		
Farameter	Symbol			typ	max	Unit
Forward Transfer Gain	S21e   <sup>2</sup> 1	V <sub>CE</sub> =1V, I <sub>C</sub> =1mA, f=1GHz	5	7.5		dB
	S21e   <sup>2</sup> 2	V <sub>CE</sub> =2V, I <sub>C</sub> =3mA, f=1GHz		11.5		dB
Noise Figure	NF1	V <sub>CE</sub> =1V, I <sub>C</sub> =1mA, f=1GHz		2.6	4.5	dB
	NF2	V <sub>CE</sub> =2V, I <sub>C</sub> =3mA, f=1GHz		1.9		dB



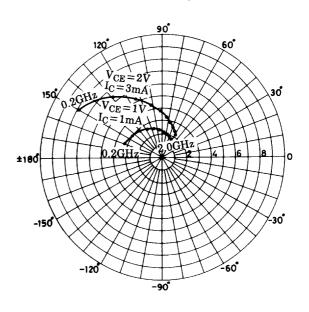


### S parameter

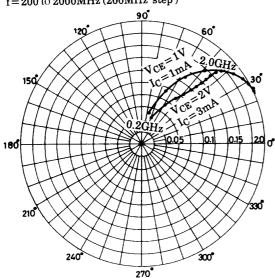
S11e f=200 to 2000MHz (200MHz step)



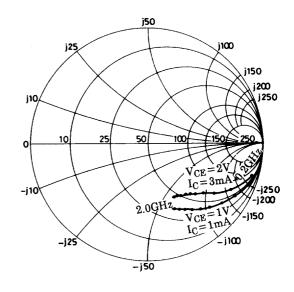
 $\begin{array}{l} S21e \\ f\!=\!200 \ \mathrm{to} \ 2000 MHz \ (200 MHz \ step \,) \end{array}$ 



S12e f=200 to 2000 MHz (200 MHz step)



 $\begin{array}{l} S22e \\ f\!=\!200 \text{ to } 2000 \text{MHz} \, (200 \text{MHz step}\,) \end{array}$ 



#### 2SC4855

#### S parameter (Common emitter)

 $V_{CE}=1V, I_{C}=1mA, Z_{O}=50\Omega$ 

Freq (MHz)	S <sub>11</sub>	∠S <sub>11</sub>	S <sub>21</sub>	∠S <sub>21</sub>	S <sub>12</sub>	∠S <sub>12</sub>	S <sub>22</sub>	∠S <sub>22</sub>
200	0.944	-18.0	3.276	159.9	0.050	76.8	0.981	-12.0
400	0.869	-34.2	3.037	143.8	0.093	65.5	0.928	-22.2
600	0.786	-48.9	2.778	130.2	0.128	56.5	0.865	-31.1
800	0.706	-62.0	2.550	117.6	0.155	48.8	0.808	-38.6
1000	0.619	-75.4	2.379	106.1	0.173	42.3	0.753	-45.7
1200	0.547	-87.4	2.165	95.7	0.186	36.9	0.712	-51.2
1400	0.473	-100.1	2.022	85.9	0.194	32.4	0.675	-56.1
1600	0.417	-111.7	1.840	77.4	0.198	28.9	0.639	-60.4
1800	0.371	-125.2	1.745	69.9	0.202	26.4	0.614	-64.1
2000	0.343	-139.3	1.639	62.2	0.201	25.2	0.595	-67.6

#### $V_{CE}=2V$ , $I_{C}=3mA$ , $Z_{O}=50\Omega$

Freq (MHz)	S <sub>11</sub>	∠S <sub>11</sub>	S <sub>21</sub>	∠S <sub>21</sub>	S <sub>12</sub>	∠S <sub>12</sub>	S <sub>22</sub>	∠S <sub>22</sub>
200	0.844	-30.5	7.785	149.6	0.043	71.0	0.933	-17.4
400	0.688	-53.7	6.308	129.2	0.072	59.3	0.808	-28.8
600	0.545	-72.1	5.182	113.8	0.091	52.6	0.705	-36.3
800	0.451	-86.7	4.315	102.3	0.104	49.2	0.632	-41.6
1000	0.374	-102.0	3.713	95.2	0.117	47.0	0.590	-46.0
1200	0.308	-115.4	3.225	83.5	0.127	45.9	0.564	-49.5
1400	0.260	-130.6	2.823	75.5	0.137	45.0	0.541	-53.1
1600	0.230	-145.2	2.515	68.8	0.146	44.5	0.525	-56.8
1800	0.215	-160.5	2.296	63.0	0.155	44.2	0.510	-60.3
2000	0.213	-177.0	2.143	56.9	0.166	43.8	0.506	-63.4

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